3 Ω, High Bandwidth, Dual SPDT Analog Switch

DESCRIPTION

The DG2517/DG2518 are low-voltage dual single-pole/double-throw monolithic CMOS analog switches. Designed to operate from 1.8 V to 5.5 V power supply, the DG2517/DG2518 achieves a bandwidth of 157 MHz while providing low on-resistance (3 Ω), excellent on-resistance matching (0.2 Ω) and flatness (1 Ω) over the entire signal range.

The DG2517/DG2518 offers the advantage of high linearity that reduces signal distortion, making ideal for audio, video, and USB signal routing applications. Additionally, the DG2517/DG2518 are 1.6 V logic compatible within the full operation voltage range.

Built on Vishay Siliconix's proprietary sub-micron high-density process, the DG2517/DG2518 brings low power consumption at the same time as reduces PCB spacing with the MSOP10 and DFN10 packages.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations. The DFN package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The MSOP package uses 100 % matte Tin device termination and is represented by the lead (Pb)- free "-E3" suffix. Both the matte Tin and nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

FEATURES

- 1.8 to 5.5 V Single Supply Operation
- Low Ron: 3 Ω at 4.2 V
- 157 MHz, - 3 dB Bandwidth
- Low Off-Isolation, - 47 dB at 10 MHz
- + 1.6 V Logic Compatible

Pb-free
RoHS
COMPLIANT

BENEFITS

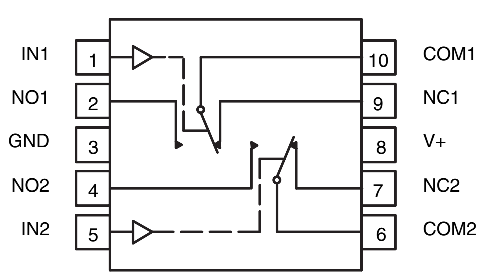
- High Linearity
- Low Power Consumption
- High Bandwidth
- Full Rail Signal Swing Range

APPLICATIONS

- USB/UART Signal Switching
- Audio/Video Switching
- Cellular Phone
- Media Players
- Modems
- Hard Drives
- PCMCIA

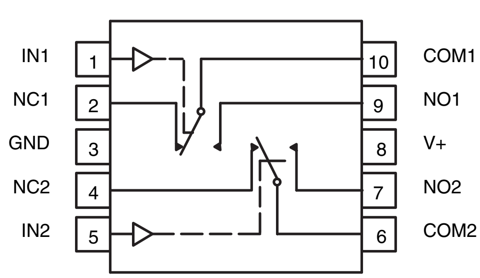
FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG2517



Top View

DG2518



Top View

TRUTH TABLE		
Logic	**NC1 and NC2**	**NO1 and NO2**
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION		
Temp Range	**Package**	**Part Number**
- 40 to 85 °C	MSOP-10	DG2517DQ-T1-E3
		DG2518DQ-T1-E3
	DFN-10	DG2517DN-T1-E4
		DG2518DN-T1-E4

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
Reference to GND			
V+		- 0.3 to + 6	V
IN, COM, NC, NO[a]		- 0.3 to (V+ + 0.3)	
Continuous Current (Any terminal)		± 50	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 200	
Storage Temperature (D Suffix)		- 65 to 150	°C
Power Dissipation (Packages)[b]	MSOP-10[c]	320	mW
	DFN-10[d]	1191	

Notes:
a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate 4.0 mW/°C above 70 °C.
d. Derate 14.9 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 3 V, ± 10 %, V_{IN} = 0.5 or 1.4 V[e]		Temp[a]	Limits - 40 to 85 °C Min[b]	Typ[c]	Max[b]	Unit
Analog Switch								
Analog Signal Range[d]	V_{NO}, V_{NC}, V_{COM}			Full	0		V+	V
On-Resistance	r_{ON}	V+ = 2.7 V, V_{COM} = 1.5 V, $I_{NO/NC}$ = 10 mA		Room Full		3.2	4.5 5.0	Ω
r_{ON} Flatness	r_{ON} Flatness	V+ = 2.7 V, V_{COM} = 1.5, 2 V, $I_{NO/NC}$ = 10 mA		Room Full		1.0	1.4 16	
r_{ON} Match Between Channels	Δr_{ON}	V+ = 2.7 V, V_{COM} = 1.5 V, $I_{NO/NC}$ = 10 mA		Room Full		0.1	0.3 0.4	
Switch Off Leakage Current[f]	$I_{NO(off)}$, $I_{NC(off)}$	V+ = 3.6 V, V_{NO}, V_{NC} = 0.3 V/ 3 V, V_{COM} = 3 V/0.3 V		Room Full	- 1 - 10		1 10	nA
	$I_{COM(off)}$			Room Full	- 1 - 10		1 10	
Channel-On Leakage Current[f]	$I_{COM(on)}$	V+ = 3.6 V, $V_{NO,}$ V_{NC} = V_{COM} = 0.3 V/3 V		Room Full	- 1 - 10		1 10	
Digital Control								
Input High Voltage[d]	V_{INH}			Full	1.4			V
Input Low Voltage	V_{INL}			Full			0.5	
Input Capacitance	C_{in}			Full		4		pF
Input Current	I_{INL} or I_{INH}			Full	1		1	µA
Dynamic Characteristics								
Turn-On Time	t_{ON}	V+ = 2.7 V, V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω, C_L = 35 pF		Room Full		15	30 50	ns
Turn-Off Time	t_{OFF}			Room Full		10	25 35	
Break-Before-Make Time	t_d	V_{NO} or V_{NC} = 1.5 V, R_L = 300 Ω, C_L = 35 pF		Full	1			
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 1.5 V, R_{GEN} = 0 Ω		Room		1		pC
- 3 dB Bandwidth	BW	0 dBm, C_L = 5 pF, R_L = 50 Ω		Room		157		MHz
Off-Isolation[d]	OIRR	R_L = 50 Ω, C_L = 5 pF	f = 1 MHz	Room		- 67		dB
			f = 10 MHz	Room		- 47		
Crosstalk[d]	X_{TALK}	R_L = 50 Ω, C_L = 5 pF	f = 1 MHz	Room		- 67		
			f = 10 MHz	Room		- 47		
N_O, N_C Off Capacitance[d]	$C_{NO(off)}$	V_{IN} = 0 or V+, f = 1 MHz		Room		8		pF
	$C_{NC(off)}$			Room		8		
Channel-On Capacitance[d]	$C_{NO(on)}$			Room		35		
	$C_{NC(on)}$			Room		35		
Power Supply								
Power Supply Current	I+	V_{IN} = 0 or V+		Full		0.01	1.0	µA

Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. Typical values are for design aid only, not guaranteed nor subject to production testing.
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Guaranteed by 5 V leakage testing, not production tested.

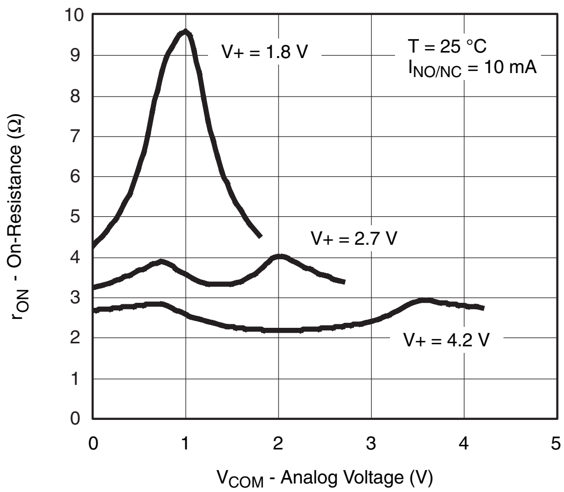
SPECIFICATIONS (V+ = 5 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified $V+ = 5\ V, \pm 10\ \%, V_{IN} = 0.8$ or $2.0\ V^{e}$	Temp[a]	Limits - 40 to 85 °C Min[b]	Typ[c]	Max[b]	Unit
Analog Switch							
Analog Signal Range[d]	V_{NO}, V_{NC}, V_{COM}		Full	0		V+	V
On-Resistance	r_{ON}	$V+ = 4.2\ V, V_{COM} = 3.5\ V, I_{NO/NC} = 10\ mA$	Room Full		3	4.0 4.3	Ω
r_{ON} Flatness	r_{ON} Flatness	$V+ = 4.2\ V, V_{COM} = 1, 2, 3.5\ V$ $I_{NO/NC} = 10\ mA$	Room Full		1.1	1.4 1.6	Ω
r_{ON} Match Between Channels	Δr_{ON}	$V+ = 4.2\ V, V_{COM} = 3.5\ V, I_{NO/NC} = 10\ mA$	Room Full		0.1	0.3 0.4	Ω
Switch Off Leakage Current	$I_{NO(off)}$, $I_{NC(off)}$	$V+ = 5.5\ V$ $V_{NO}, V_{NC} = 1\ V/4.5\ V, V_{COM} = 4.5\ V/1\ V$	Room Full	- 1 - 10		1 10	nA
	$I_{COM(off)}$		Room Full	- 1 - 10		1 10	nA
Channel-On Leakage Current	$I_{COM(on)}$	$V+ = 5.5\ V, V_{COM} = V_{NO}, V_{NC} = 1\ V/4.5\ V$	Room Full	- 1 - 10		1 10	nA
Digital Control							
Input High Voltage[d]	V_{INH}		Full	2.0			V
Input Low Voltage	V_{INL}		Full			0.8	V
Input Capacitance	C_{in}		Full		4		pF
Input Current	I_{INL} or I_{INH}	$V_{IN} = 0\ V$ or V+	Full	1		1	µA
Dynamic Characteristics							
Turn-On Time	t_{ON}	$V+ = 4.2\ V, V_{NO}$ or $V_{NC} = 3\ V$ $R_L = 300\ \Omega, C_L = 35\ pF$	Room Full		12	25 45	ns
Turn-Off Time	t_{OFF}		Room Full		8	20 30	ns
Break-Before-Make Time	t_d	V_{NO} or $V_{NC} = 3\ V, R_L = 300\ \Omega, C_L = 35\ pF$	Full	1			ns
Charge Injection[d]	Q_{INJ}	$C_L = 1\ nF, V_{GEN} = 2.5\ V, R_{GEN} = 0\ \Omega$	Room		2		pC
- 3 dB Bandwidth	BW	$0\ dBm, C_L = 5\ pF, R_L = 50\ \Omega$	Room		157		MHz
Off-Isolation[d]	OIRR	$R_L = 50\ \Omega, C_L = 5\ pF$, f = 1 MHz	Room		- 67		dB
		f = 10 MHz	Room		- 47		dB
Crosstalk[d]	X_{TALK}	$R_L = 50\ \Omega, C_L = 5\ pF$, f = 1 MHz	Room		- 67		dB
		f = 10 MHz	Room		- 47		dB
Source-Off Capacitance[d]	$C_{NO(off)}$	$V_{IN} = 0$ or V+, f = 1 MHz	Room		8		pF
	$C_{NC(off)}$		Room		8		pF
Channel-On Capacitance[d]	$C_{NO(on)}$		Room		35		pF
	$C_{NC(on)}$		Room		35		pF
Power Supply							
Power Supply Range	V+			1.8		5.5	V
Power Supply Current	I+	$V_{IN} = 0$ or V+	Full		0.01	1.0	µA

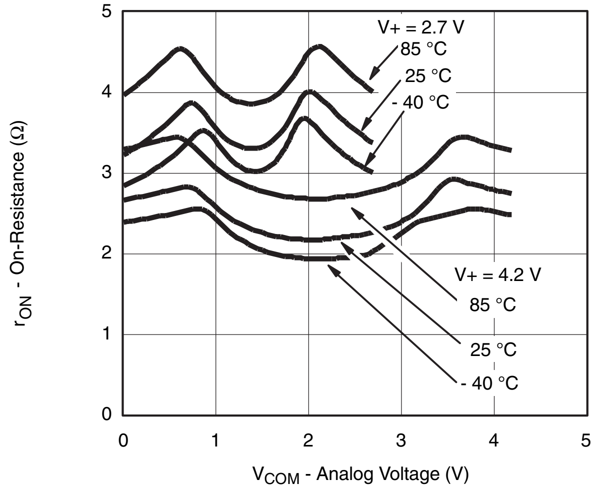
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. Typical values are for design aid only, not guaranteed nor subject to production testing.
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

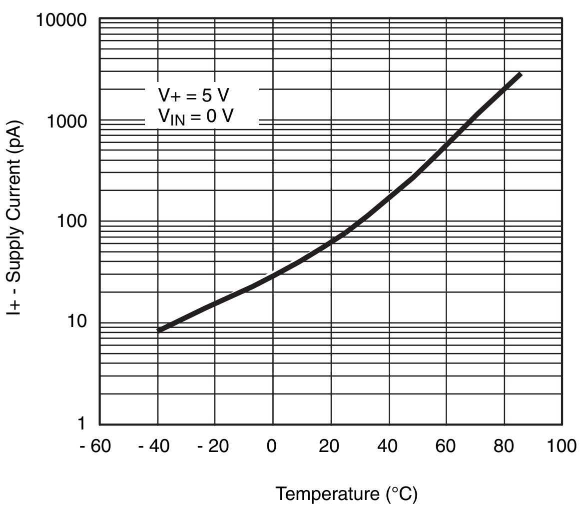
TYPICAL CHARACTERISTICS 25 °C, unless noted



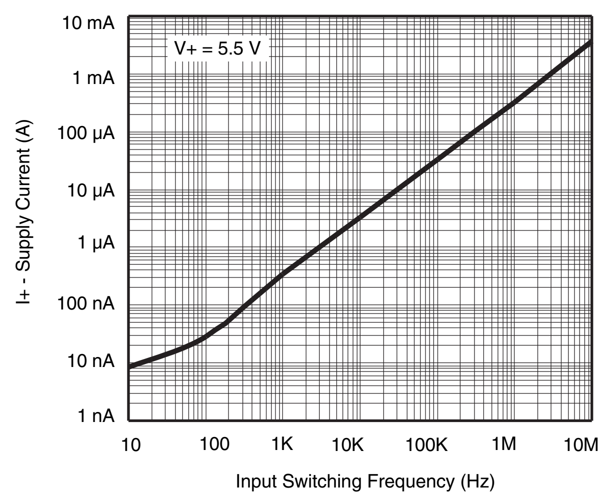
r_{ON} vs. V_{COM} and Supply Voltage



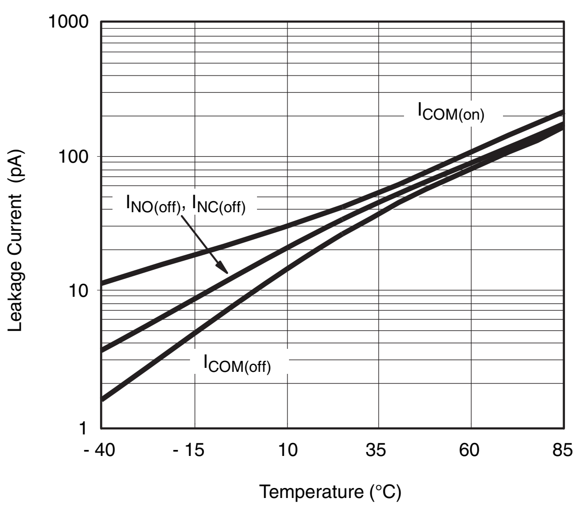
r_{ON} vs. Analog Voltage and Temperature



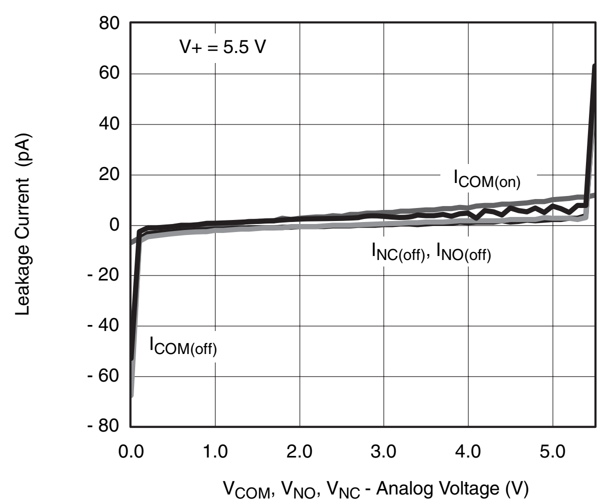
Supply Current vs. Temperature



Supply Current vs. Input Switching Frequency

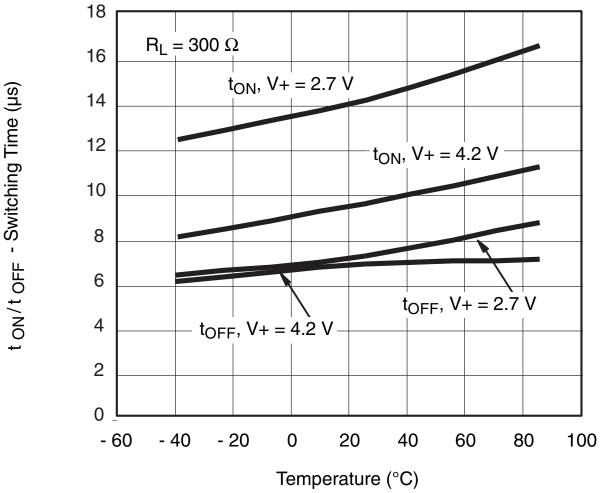


Leakage Current vs. Temperature

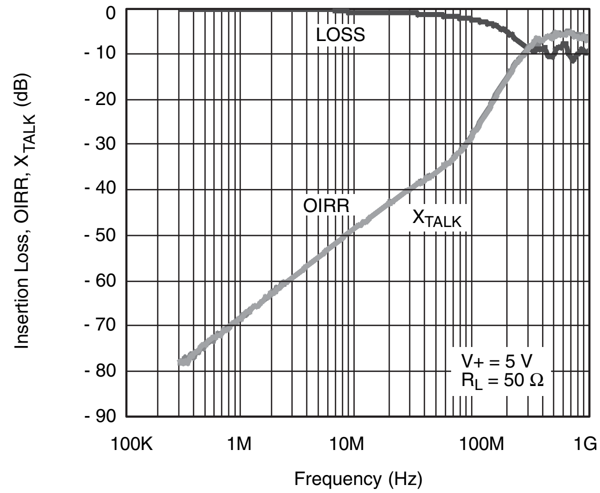


Leakage vs. Analog Voltage

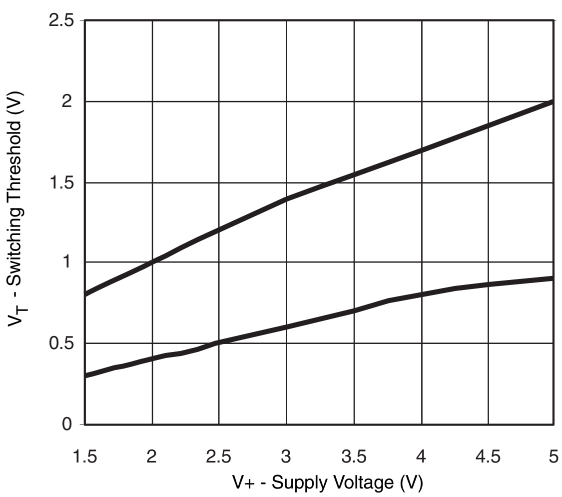
TYPICAL CHARACTERISTICS 25 °C, unless noted



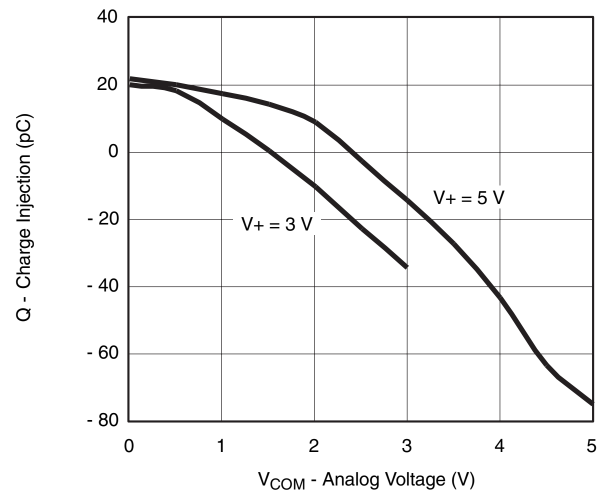
Switching Time vs. Temperature



Insertion Loss, Off-Isolation Crosstalk vs. Frequency

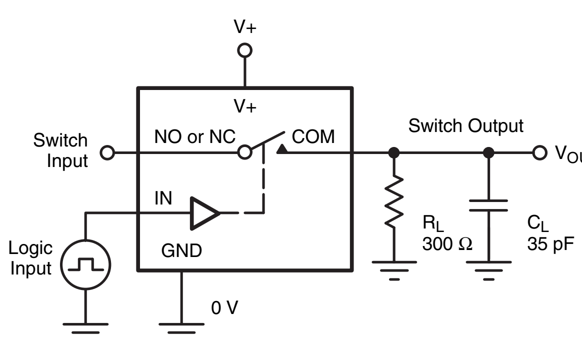


Switching Threshold vs. Supply Voltage



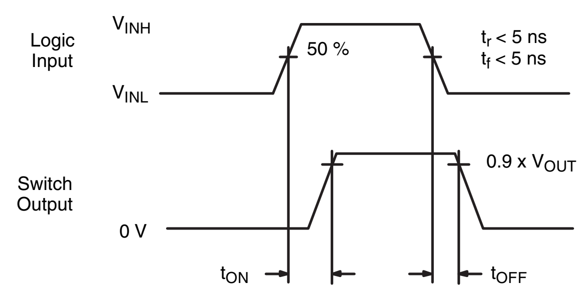
Charge Injection vs. Analog Voltage

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

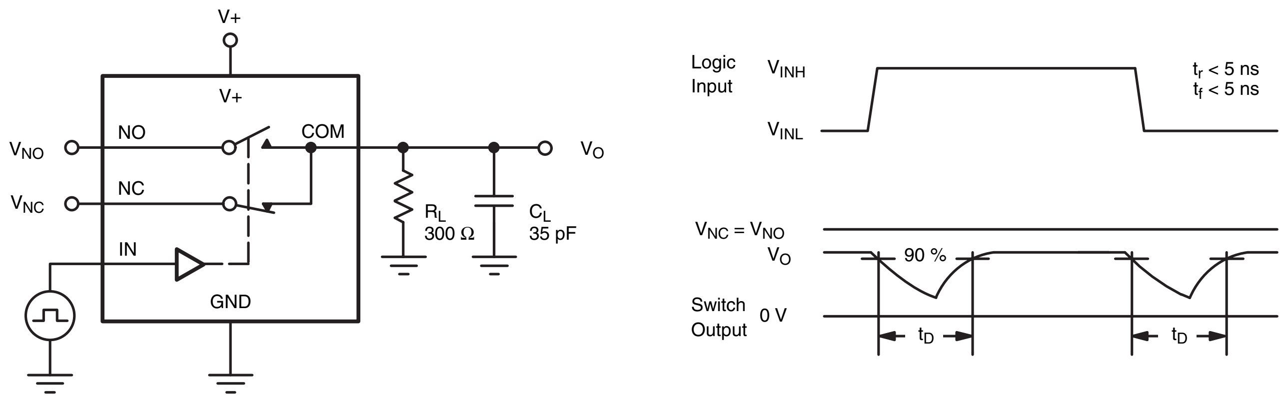
$$V_{OUT} = V_{COM}\left(\frac{R_L}{R_L + R_{ON}}\right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

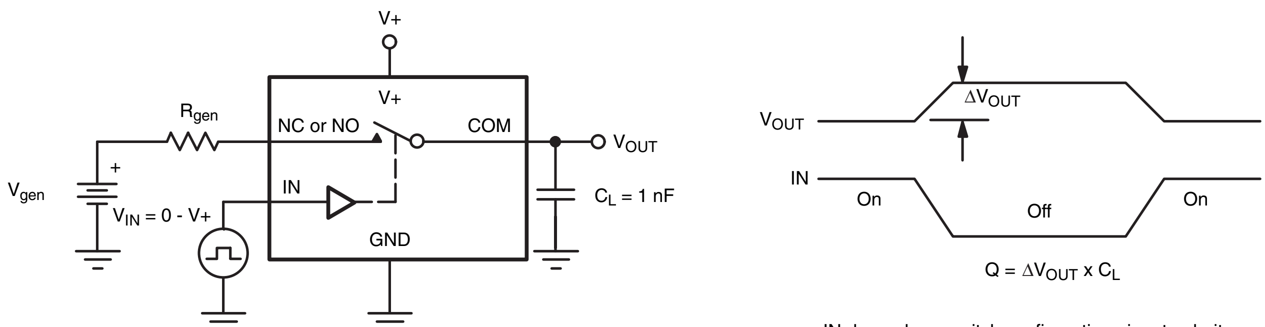
Figure 1. Switching Time

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

Figure 2. Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

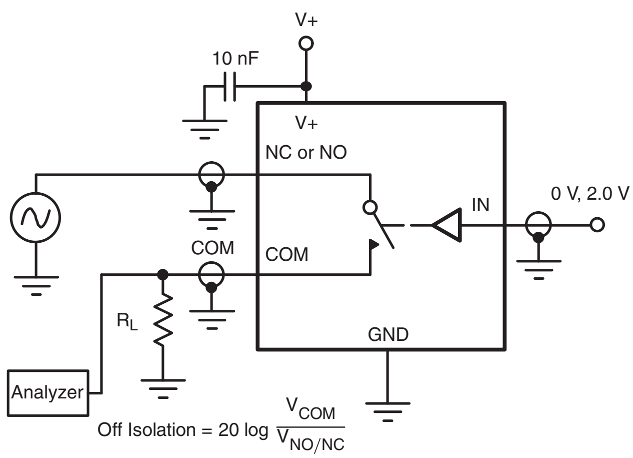


Figure 4. Off-Isolation

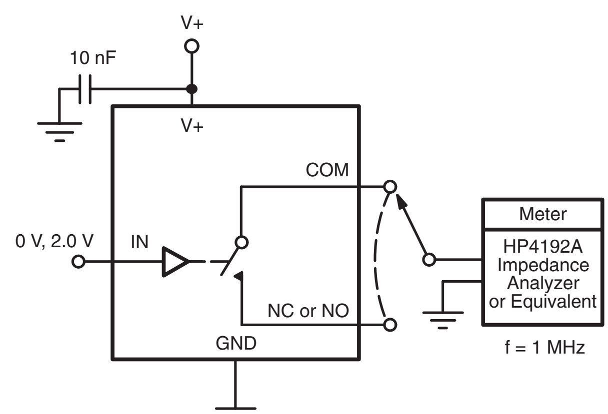


Figure 5. Channel Off/On Capacitance

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